NSN 5961-01-019-2180

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View Online at https://aerobasegroup.com/nsn/5961-01-019-2180 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case and low power **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage/static/emitter open and 3.0 emitter to base voltage, static, collector open and 15.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current **Transfer Ratio:** 46.0 static forward current transfer ratio, common-emitter and 65.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Special Test Features:** Tested and selected for transfer ratio. **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

Fiig:

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